

Brushless DC Motor Controller

The MC33033 is a high performance second generation, limited feature, monolithic brushless dc motor controller which has evolved from Motorola's full featured MC33034 and MC33035 controllers. It contains all of the active functions required for the implementation of open loop, three or four phase motor control. The device consists of a rotor position decoder for proper commutation sequencing, temperature compensated reference capable of supplying sensor power, frequency programmable sawtooth oscillator, fully accessible error amplifier, pulse width modulator comparator, three open collector top drivers, and three high current totem pole bottom drivers ideally suited for driving power MOSFETs. Unlike its predessors, it does not feature separate drive circuit supply and ground pins, brake input, or fault output signal.

Included in the MC33033 are protective features consisting of undervoltage lockout, cycle–by–cycle current limiting with a selectable time delayed latched shutdown mode, and internal thermal shutdown.

Typical motor control functions include open loop speed, forward or reverse direction, and run enable. The MC33033 is designed to operate brushless motors with electrical sensor phasings of $60^{\circ}/300^{\circ}$ or $120^{\circ}/240^{\circ}$, and can also efficiently control brush dc motors.

- 10 to 30 V Operation
- Undervoltage Lockout
- 6.25 V Reference Capable of Supplying Sensor Power
- Fully Accessible Error Amplifier for Closed Loop Servo Applications
- High Current Drivers Can Control External 3-Phase MOSFET Bridge
- Cycle–By–Cycle Current Limiting
- Internal Thermal Shutdown
- Selectable 60°/300° or 120°/240° Sensor Phasings
- Also Efficiently Control Brush DC Motors with External MOSFET H–Bridge

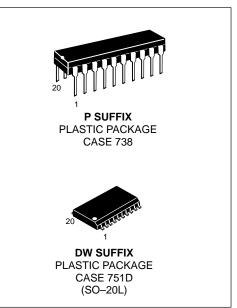
ORDERING INFORMATION

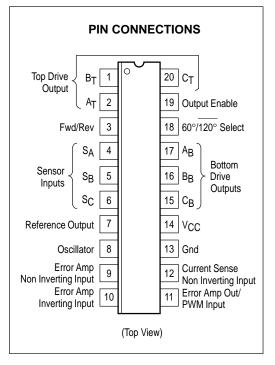
Device	Operating Temperature Range	Package
MC33033DW	T. 40% to 1.95%	SO-20L
MC33033P	$T_A = -40^\circ$ to $+85^\circ$ C	Plastic DIP

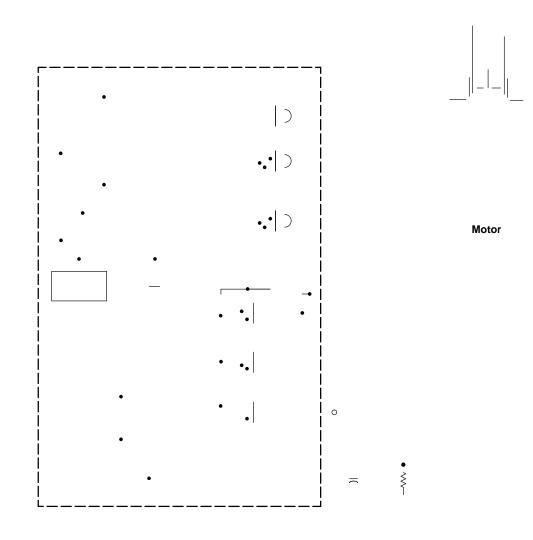
BRUSHLESS DC MOTOR CONTROLLER

MC33033

SEMICONDUCTOR TECHNICAL DATA







MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	Vcc	30	V
Digital Inputs (Pins 3, 4, 5, 6, 18, 19)	-	V _{ref}	V
Oscillator Input Current (Source or Sink)	losc	30	mA
Error Amp Input Voltage Range (Pins 9, 10, Note 1)	VIR	-0.3 to V _{ref}	V
Error Amp Output Current (Source or Sink, Note 2)	lOut	10	mA
Current Sense Input Voltage Range	V _{Sense}	-0.3 to 5.0	V
Top Drive Voltage (Pins 1, 2, 20)	VCE(top)	40	V
Top Drive Sink Current (Pins 1, 2, 20)	ISink(top)	50	mA
Bottom Drive Output Current (Source or Sink, Pins 15,16, 17)	IDRV	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Dual–In–Line, Case 738 Maximum Power Dissipation @ T _A = 85°C Thermal Resistance, Junction–to–Air DW Suffix, Surface Mount, Case 751D	PD R _θ JA	867 75	mW °C/W
Maximum Power Dissipation @ T _A = 85°C Thermal Resistance, Junction–to–Air	PD R _{θJA}	619 105	mW °C/W
Operating Junction Temperature	TJ	150	°C
Operating Ambient Temperature Range	ТА	-40 to +85	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

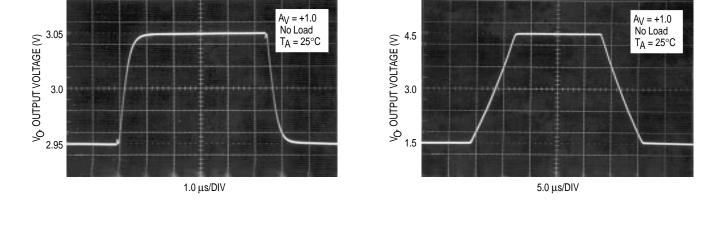
ELECTRICAL CHARACTERISTICS (V_{CC} = 20 V, R_T = 4.7 k, C_T = 10 nF, T_A = 25°C, unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
REFERENCE SECTION			•		·
Reference Output Voltage (I _{ref} = 1.0 mA) $T_A = 25^{\circ}C$ $T_A = -40^{\circ}$ to + 85°C	V _{ref}	5.9 5.82	6.24 _	6.5 6.57	V
Line Regulation (V _{CC} = 10 V to 30 V, I_{ref} = 1.0 mA)	Reg _{line}	_	1.5	30	mV
Load Regulation (I _{ref} = 1.0 mA to 20 mA)	Reg _{load}	-	16	30	mV
Output Short-Circuit Current (Note 3)	ISC	40	75	-	mA
Reference Under Voltage Lockout Threshold	V _{th}	4.0	4.5	5.0	V
ERROR AMPLIFIER			•		
Input Offset Voltage (T _A = -40° to + 85° C)	VIO	-	0.4	10	mV
Input Offset Current ($T_A = -40^\circ$ to + 85°C)	IIO	_	8.0	500	nA
Input Bias Current (T _A = -40° to + 85° C)	I _{IB}	_	-46	-1000	nA
Input Common Mode Voltage Range	VICR		(0 V to V _{ref)}		V
Open Loop Voltage Gain (V _O = 3.0 V, R _L = 15 k)	Avol	70	80	-	dB
Input Common Mode Rejection Ratio	CMRR	55	86	_	dB
Power Supply Rejection Ratio (V_{CC} = 10 V to 30 V)	PSRR	65	105	-	dB
Output Voltage Swing High State ($R_L = 15 \text{ k to Gnd}$) Low State ($R_L = 17 \text{ k to V}_{ref}$)	Voh Vol	4.6	5.3 0.5	_ 1.0	V

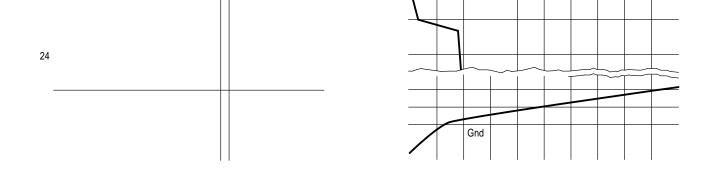
NOTES: 1. The input common mode voltage or input signal voltage should not be allowed to go negative by more than 0.3 V.
2. The compliance voltage must not exceed the range of -0.3 to V_{ref}.
3. Maximum package power dissipation limits must be observed.

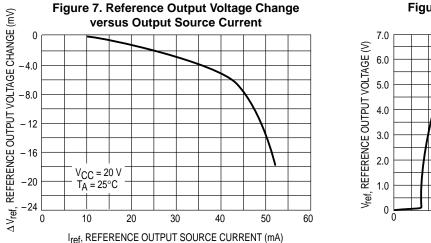
ELECTRICAL CHARACTERISTICS (continued) ($V_{CC} = 20 V$,	RT = 4.7 k, CT	[.] = 10 nF, T _A =	25°C, unless otherwise noted.)
--	----------------	--	--------------------------------

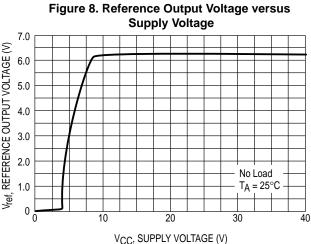
Characteristic	Symbol	Min	Тур	Max	Unit
OSCILLATOR SECTION			-71-		
Oscillator Frequency	fOSC	22	25	28	kHz
Frequency Change with Voltage (V _{CC} = 10 V to 30 V)	Δf _{OSC} /ΔV		0.01	5.0	%
Sawtooth Peak Voltage	VOSC(P)	_	4.1	4.5	V
Sawtooth Valley Voltage	VOSC(V)	1.2	1.5	_	V
	1000(1)				
Input Threshold Voltage (Pins 3, 4, 5, 6, 18, 19) High State Low State	VIH VIL	3.0 -	2.2 1.7	_ 0.8	V
Sensor Inputs (Pins 4, 5, 6) High State Input Current (V _{IH} = 5.0 V) Low State Input Current (V _{IL} = 0 V)	IIH IIL	-150 -600	-70 -337	-20 -150	μΑ
Forward/Reverse, $60^{\circ}/120^{\circ}$ Select and Output Enable (Pins 3, 18, 19) High State Input Current (V _{IH} = 5.0 V) Low State Input Current (V _{IL} = 0 V)	IIH IIL	-75 -300	-36 -175	-10 -75	μΑ
CURRENT-LIMIT COMPARATOR					
Threshold Voltage	V _{th}	85	101	115	mV
Input Common Mode Voltage Range	VICR	_	3.0	-	V
Input Bias Current	I _{IB}	_	-0.9	-5.0	μΑ
OUTPUTS AND POWER SECTIONS					
Top Drive Output Sink Saturation (ISink = 25 mA)	V _{CE(sat)}	-	0.5	1.5	V
Top Drive Output Off–State Leakage (V_{CE} = 30 V)	IDRV(leak)	-	0.06	100	μΑ
Top Drive Output Switching Time (C_L = 47 pF, R_L = 1.0 k) Rise Time Fall Time	t _r t _f	-	107 26	300 300	ns
Bottom Drive Output Voltage High State (V _{CC} = 30 V, I_{source} = 50 mA) Low State (V _{CC} = 30 V, I_{sink} = 50 mA)	Voh Vol	(V _{CC} – 2.0) –	(V _{CC} – 1.1) 1.5	_ 2.0	V
Bottom Drive Output Switching Time (C _L = 1000 pF) Rise Time Fall Time	t _r t _f		38 30	200 200	ns
Under Voltage Lockout Drive Output Enabled (V _{CC} Increasing) Hysteresis	V _{th(on)} V _H	8.2 0.1	8.9 0.2	10 0.3	V
Power Supply Current	ICC	-	15	22	mA



5







ΔVref. NORMALIZED REFERENCE VOLTAGE CHANGE (mV) Figure 9. Reference Output Voltage versus Temperature 40 20 0 -20 V_{CC} = 20 V No Load 40 -55 -25 0 25 50 75 100 125 TA, AMBIENT TEMPERATURE (°C)

Figure 11. Bottom Drive Response Time versus Current Sense Input Voltage

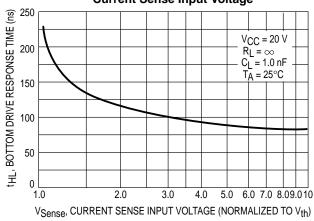


Figure 10. Output Duty Cycle versus PWM Input Voltage

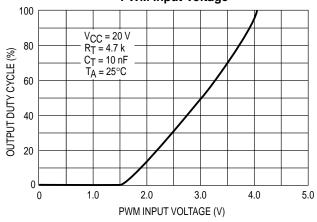
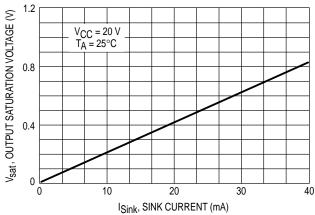
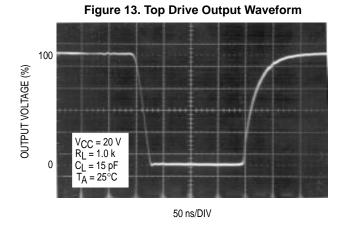
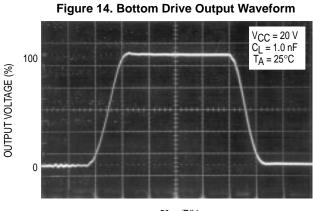


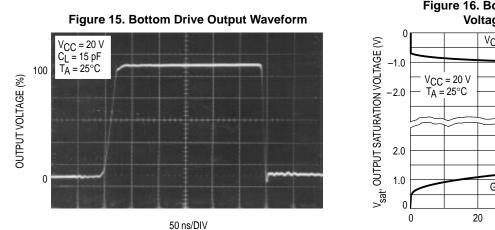
Figure 12. Top Drive Output Saturation Voltage versus Sink Current

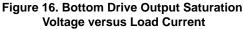


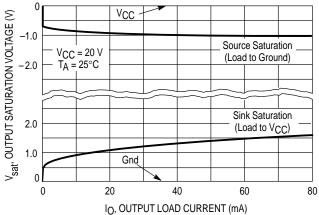


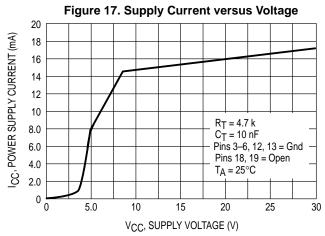


50 ns/DIV











PIN FUNCTION DESCRIPTION

Pin	Symbol	Description
1, 2, 20	Β _T , Α _T , C _T	These three open collector Top Drive Outputs are designed to drive the external upper power switch transistors.
3	Fwd//Rev	The Forward/Reverse Input is used to change the direction of motor rotation.
4, 5, 6	S _A , S _B , S _C	These three Sensor Inputs control the commutation sequence.
7	Reference Output	This output provides charging current for the oscillator timing capacitor C_T and a reference for the Error Amplifier. It may also serve to furnish sensor power.
8	Oscillator	

INTRODUCTION

The MC33033 is one of a series of high performance monolithic dc brushless motor controllers produced by Motorola. It contains all of the functions required to implement a limited–feature, open loop, three or four phase motor control system. Constructed with Bipolar Analog technology, it offers a high degree of performance and ruggedness in hostile industrial environments. The MC33033 contains a rotor position decoder for proper commutation sequencing, a temperature compensated reference capable of supplying sensor power, a frequency programmable sawtooth oscillator, a fully accessible error amplifier, a pulse width modulator comparator, three open collector top drive outputs, and three high current totem pole bottom driver outputs ideally suited for driving power MOSFETs.

Included in the MC33033 are protective features consisting of undervoltage lockout, cycle-by-cycle current limiting with a latched shutdown mode, and internal thermal shutdown.

Typical motor control functions include open loop speed control, forward or reverse rotation, and run enable. In addition, the MC33033 has a $60^{\circ}/120^{\circ}$ select pin which configures the rotor position decoder for either 60° or 120° sensor electrical phasing inputs.

FUNCTIONAL DESCRIPTION

A representative internal block diagram is shown in Figure 18, with various applications shown in Figures 34, 36, 37, 41, 43, and 44. A discussion of the features and function of each of the internal blocks given below and referenced to Figures 18 and 36.

Rotor Position Decoder

An internal rotor position decoder monitors the three sensor inputs (Pins 4, 5, 6) to provide the proper sequencing of the top and bottom drive outputs. The Sensor Inputs are designed to interface directly with open collector type Hall Effect switches or opto slotted couplers. Internal pull-up resistors are included to minimize the required number of external components. The inputs are TTL compatible, with their thresholds typically at 2.2 V. The MC33033 series is designed to control three phase motors and operate with four of the most common conventions of sensor phasing. A 60°/120° Select (Pin 18) is conveniently provided which affords the MC33033 to configure itself to control motors having either 60°, 120°, 240° or 300° electrical sensor phasing. With three Sensor Inputs there are eight possible input code combinations, six of which are valid rotor positions. The remaining two codes are invalid and are usually caused by an open or shorted sensor line. With six valid input codes, the decoder can resolve the motor rotor position to within a window of 60 electrical degrees.

The Forward/Reverse input (Pin 3) is used to change the direction of motor rotation by reversing the voltage across the stator winding. When the input changes state, from high to low with a given sensor input code (for example 100), the enabled top and bottom drive outputs with the same alpha designation are exchanged (A_T to A_B, B_T to B_B, C_T to C_B). In

effect the commutation sequence is reversed and the motor changes directional rotation.

Motor on/off control is accomplished by the Output Enable (Pin19). When left disconnected, an internal pull–up resistor to a positive source enables sequencing of the top and bottom drive outputs. When grounded, the Top Drive Outputs turn off and the bottom drives are forced low, causing the motor to coast.

The commutation logic truth table is shown in Figure 19. In half wave motor drive applications, the Top Drive Outputs are not required and are typically left disconnected.

Error Amplifier

A high performance, fully compensated Error Amplifier with access to both inputs and output (Pins 9, 10, 11) is provided to facilitate the implementation of closed loop motor speed control. The amplifier features a typical dc voltage gain of 80 dB, 0.6 MHz gain bandwidth, and a wide input common mode voltage range that extends from ground to V_{ref} . In most open loop speed control applications, the amplifier is configured as a unity gain voltage follower with the Noninverting Input connected to the speed set voltage source. Additional configurations are shown in Figures 29 through 33.

Oscillator

The frequency of the internal ramp oscillator is programmed by the values selected for timing components R_T and C_T . Capacitor C_T is charged from the Reference Output (Pin 7) through resistor R_T and discharged by an internal discharge transistor. The ramp peak and valley voltages are typically 4.1 V and 1.5 V respectively. To provide a good compromise between audible noise and output switching efficiency, an oscillator frequency in the range of 20 to 30 kHz is recommended. Refer to Figure 1 for component selection.

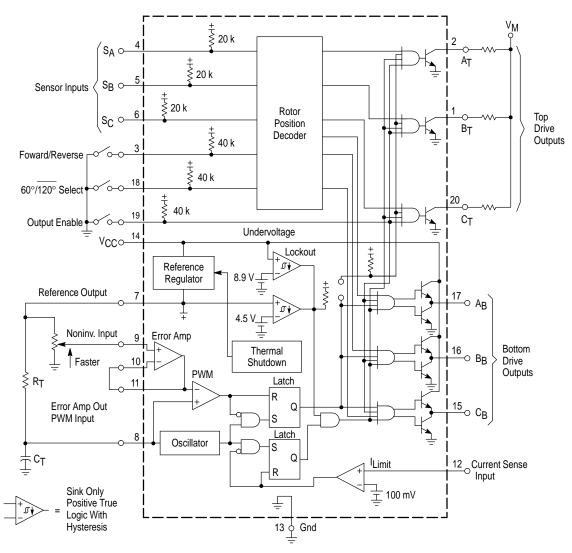
Pulse Width Modulator

The use of pulse width modulation provides an energy efficient method of controlling the motor speed by varying the average voltage applied to each stator winding during the commutation sequence. As C_T discharges, the oscillator sets both latches, allowing conduction of the Top and Bottom Drive Outputs. The PWM comparator resets the upper latch, terminating the Bottom Drive Output conduction when the positive–going ramp of C_T becomes greater than the Error Amplifier output. The pulse width modulator timing diagram is shown in Figure 20. Pulse width modulation for speed control appears only at the Bottom Drive Outputs.

Current Limit

Continuous operation of a motor that is severely over-loaded results in overheating and eventual failure. This destructive condition can best be prevented with the use of cycle-by-cycle current limiting. That is, each on-cycle is treated as a separate event. Cycle-by-cycle current limiting is accomplished by monitoring the stator current build-up each time an output switch conducts, and upon sensing an over current condition, immediately turning off the switch and holding it off for the remaining duration of





		Outputs (Note 3)					Inputs (Note 2) Outputs (Note 3)								
	ves	tom Dri	Bot	es	op Drive	Тс				e 4)	ng (Note	Phasir	ectrical	nsor El	Se
							Current				120 °			60 °	
	СB	BB	AB	СT	Вт	AT	Sense	Enable	F/R	sc	SB	SA	sc	SB	SA
(Note 5)	1	0	0	1	1	0	0	1	1	0	0	1	0	0	1
F/R = 1	1	0	0	1	0	1	0	1	1	0	1	1	0	1	1
	0	0	1	1	0	1	0	1	1	0	1	0	1	1	1
	0	0	1	0	1	1	0	1	1	1	1	0	1	1	0
	0	1	0	0	1	1	0	1	1	1	0	0	1	0	0
	0	1	0	1	1	0	0	1	1	1	0	1	0	0	0
(Note 5)	0	0	1	0	1	1	0	1	0	0	0	1	0	0	1
F/R = 0	0	1	0	0	1	1	0	1	0	0	1	1	0	1	1
	0	1	0	1	1	0	0	1	0	0	1	0	1	1	1
	1	0	0	1	1	0	0	1	0	1	1	0	1	1	0
	1	0	0	1	0	1	0	1	0	1	0	0	1	0	0
	0	0	1	1	0	1	0	1	0	1	0	1	0	0	0
(Note 6)	0	0	0	1	1	1	Х	Х	Х	1	1	1	1	0	1
	0	0	0	1	1	1	Х	Х	Х	0	0	0	0	1	0
(Note 7)	0	0	0	1	1	1	Х	0	Х	V	V	V	V	V	V
(Note 8)	0	0	0	1	1	1	1	1	Х	V	V	V	V	V	V

Figure 19. Three Phase, Six Step Commutation Truth Table (Note 1)

NOTES: 1. V = Any one of six valid sensor or drive combinations.

X = Don't care

2. The digital inputs (Pins 3, 4, 5, 6, 18, 19) are all TTL compatible. The current sense input (Pin 12) has a 100 mV threshold with respect to Pin 13. A logic 0 for this input is defined as < 85 mV, and a logic 1 is > 115 mV.

3. The top drive outputs are open collector design and active in the low (0) state.

4. With 60°/120° (Pin 18) in the high (1) state, configuration is for 60° sensor electrical phasing inputs. With Pin 18 in the low (0) state, configuration is for 120° sensor electrical phasing inputs.

5. Valid 60° or 120° sensor combinations for corresponding valid top and bottom drive outputs.

6. Invalid sensor inputs; All top and bottom drives are off.

7. Valid sensor inputs with enable = 0; All top and bottom drives are off.

8. Valid sensor inputs with enable and current sense = 1; All top and bottom drives are off.

oscillator ramp-up period. The stator current is converted to a voltage by inserting a ground-referenced sense resistor R_S (Figure 34) in series with the three bottom switch transistors (Q_4 , Q_5 , Q_6). The voltage developed across the sense resistor is monitored by the current sense input (Pin 12), and compared to the internal 100 mV reference. If the current sense threshold is exceeded, the comparator resets the lower latch and terminates output switch conduction. The value for the sense resistor is:

$$\mathsf{R}_{\mathsf{S}} = \frac{0.1}{\mathsf{I}_{\mathsf{stator}}(\mathsf{max})}$$

The dual–latch PWM configuration ensures that only one single output conduction pulse occurs during any given oscillator cycle, whether terminated by the output of the Error Amplifier or the current limit comparator.

Reference

The on-chip 6.25 V regulator (Pin 7) provides charging current for the oscillator timing capacitor, a reference for the Error Amplifier, and can supply 20 mA of current suitable for directly powering sensors in low voltage applications. In higher voltage applications it may become necessary to transfer the power dissipated by the regulator off the IC. This is easily accomplished with the addition of an external pass

transistor as shown in Figure 21. A 6.25 V reference level was chosen to allow implementation of the simpler NPN circuit, where $V_{ref} - V_{BE}$ exceeds the minimum voltage required by Hall Effect sensors over temperature. With proper transistor selection, and adequate heatsinking, up to one amp of load current can be obtained.

Undervoltage Lockout

A dual Undervoltage Lockout has been incorporated to prevent damage to the IC and the external power switch transistors. Under low power supply conditions, it guarantees that the IC and sensors are fully functional, and that there is sufficient Bottom Drive Output voltage. The positive power supply to the IC (V_{CC}) is monitored to a threshold of 8.9 V. This level ensures sufficient gate drive necessary to attain low RDS(on) when interfacing with standard power MOSFET devices. When directly powering the Hall sensors from the reference, improper sensor operation can result if the reference output voltage should fall below 4.5 V. If one or both of the comparators detects an undervoltage condition, the top drives are turned off and the Bottom Drive Outputs are held in a low state. Each of the comparators contain hysteresis to prevent oscillations when crossing their respective thresholds.

Figure 20. PWM Timing Diagram

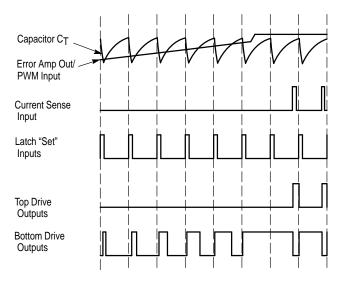
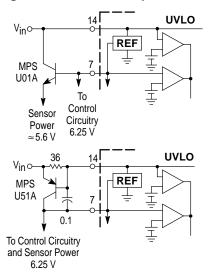
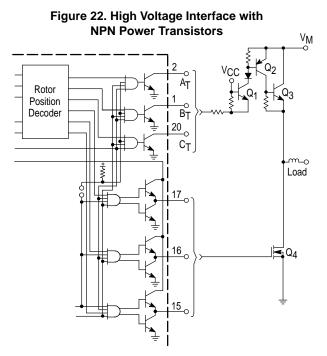


Figure 21. Reference Output Buffers



The NPN circuit is recommended for powering Hall or opto sensors, where the output voltage temperature coefficient is not critical. The PNP circuit is slightly more complex, but also more accurate. Neither circuit has current limiting.



Transistor Q₁ is a common base stage used to level shift from V_{CC} to the high motor voltage, V_M. The collector diode is required if V_{CC} is present while V_M is low.

Figure 23. High Voltage Interface with N–Channel Power MOSFETs

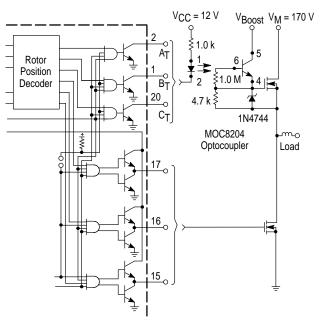
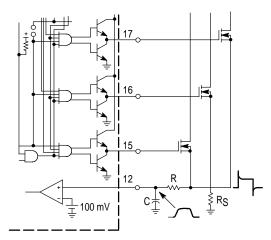
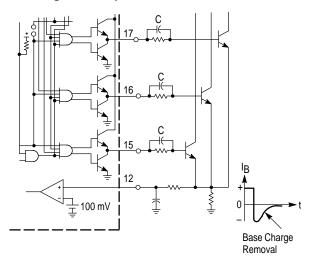


Figure 24. Current Waveform Spike Suppression



The addition of the RC filter will eliminate current–limit instability caused by the leading edge spike on the current waveform. Resistor ${\sf R}_S$ should be a low inductance type.

Figure 26. Bipolar Transistor Drive



The totem pole output can furnish negative base current for enhanced transistor turn–off, with the addition of capacitor C.



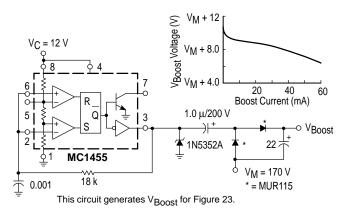
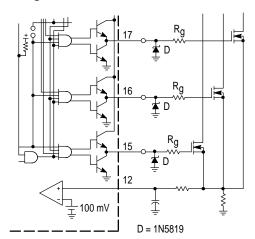
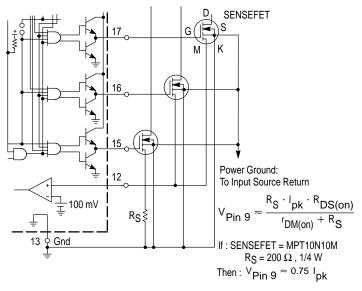


Figure 25. MOSFET Drive Precautions



Series gate resistor Rg will damp any high frequency oscillations caused by the MOSFET input capacitance and any series wiring induction in the gate–source circuit. Diode D is required if the negative current into the Bottom Drive Outputs exceeds 50 mA.

Figure 27. Current Sensing Power MOSFETs



Virtually lossless current sensing can be achieved with the implementation of SENSEFET power switches.

Figure 29. Differential Input Speed Controller

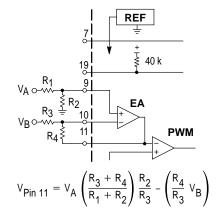
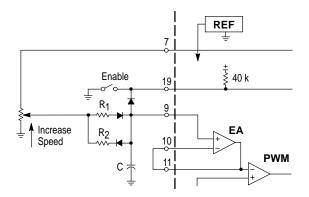
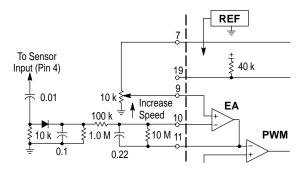


Figure 30. Controlled Acceleration/Deceleration



Resistor R₁ with capacitor C sets the acceleration time constant while R₂ controls the deceleration. The values of R₁ and R₂ should be at least ten times greater than the speed set potentiometer to minimize time constant variations with different speed settings.





The rotor position sensors can be used as a tachometer. By differentiating the positive–going edges and then integrating them over time, a voltage proportional to speed can be generated. The error amp compares this voltage to that of the speed set to control the PWM.

Drive Outputs

The three Top Drive Outputs (Pins 1, 2, 20) are open collector NPN transistors capable of sinking 50 mA with a minimum breakdown of 30 V. Interfacing into higher voltage applications is easily accomplished with the circuits shown in Figures 22 and 23.

The three totem pole Bottom Drive Outputs (Pins 15, 16, 17) are particularly suited for direct drive of N–Channel MOSFETs or NPN bipolar transistors (Figures 24, 25, 26, and 27). Each output is capable of sourcing and sinking up to 100 mA.

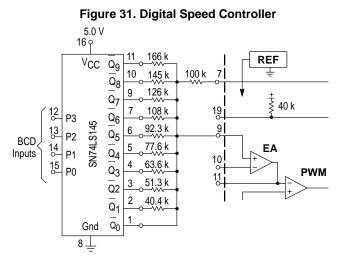
Thermal Shutdown

Internal thermal shutdown circuity is provided to protect the IC in the event the maximum junction temperature is exceeded. When activated, typically at 170°C, the IC acts as though the regulator was disabled, in turn shutting down the IC.

SYSTEM APPLICATIONS

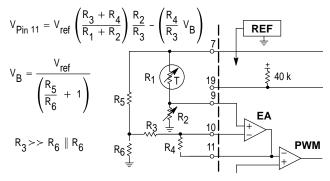
Three Phase Motor Commutation

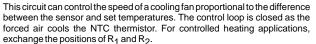
The three phase application shown in Figure 34 is an open loop motor controller with full wave, six step drive. The upper



The SN74LS145 is an open collector BCD to One of Ten decoder. When connected as shown, input codes 0000 through 1001 steps the PWM in increments of approximately 10% from 0 to 90% on–time. Input codes 1010 through 1111 will produce 100% on–time or full motor speed.

Figure 33. Closed Loop Temperature Control





power switch transistors are Darlington PNPs while the lower switches are N-Channel power MOSFETs. Each of these devices contains an internal parasitic catch diode that is used to return the stator inductive energy back to the power supply. The outputs are capable of driving a delta or wye connected stator, and a grounded neutral wye if split supplies are used. At any given rotor position, only one top and one bottom power switch (of different totem poles) is enabled. This configuration switches both ends of the stator winding from supply to ground which causes the current flow to be bidirectional or full wave. A leading edge spike is usually present on the current waveform and can cause a current-limit error. The spike can be eliminated by adding an RC filter in series with the Current Sense Input. Using a low inductance type resistor for RS will also aid in spike reduction. Figure 35 shows the commutation waveforms over two electrical cycles. The first cycle (0° to 360°) depicts motor operation at full speed while the second cycle (360° to 720°) shows a reduced speed with about 50% pulse width modulation. The current waveforms reflect a constant torque load and are shown synchronous to the commutation frequency for clarity.

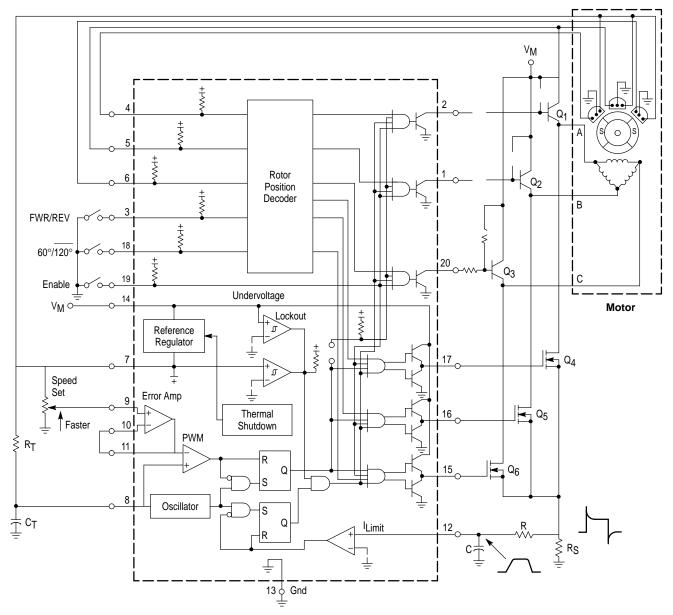
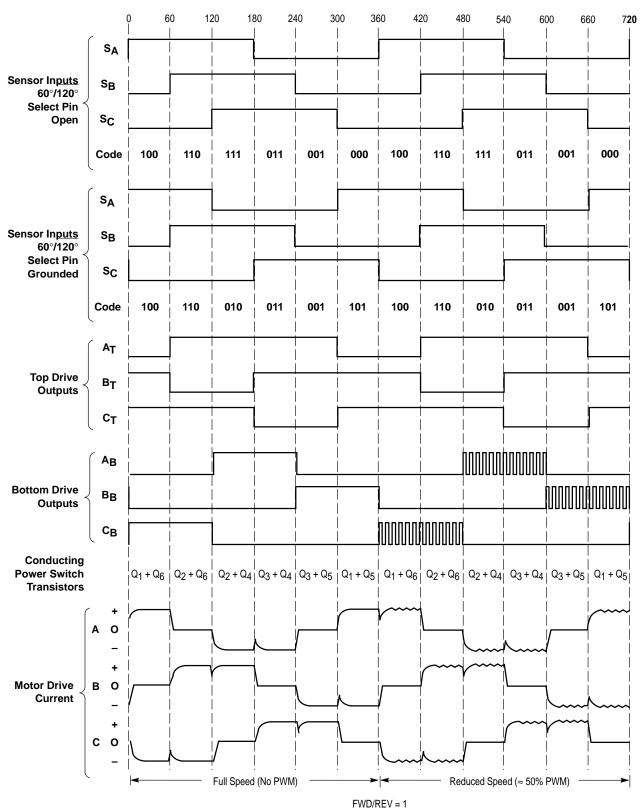


Figure 34. Three Phase, Six Step, Full Wave Motor Controller

Figure 35. Three Phase, Six Step, Full Wave Commutation Waveforms



Rotor Electrical Position (Degrees)

Figure 36 shows a three phase, three step, half wave motor controller. This configuration is ideally suited for automobile and other low voltage applications since there is only one power switch voltage drop in series with a given stator winding. Current flow is unidirectional or half wave because only one end of each winding is switched. The stator flyback voltage is clamped by a single zener and three diodes.

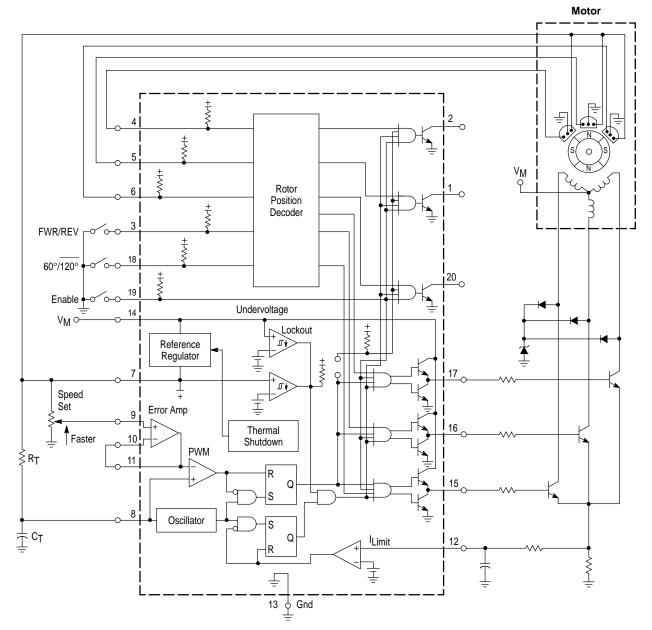


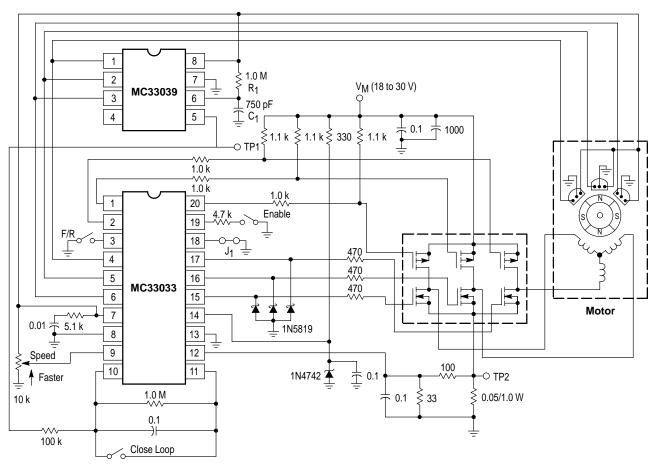
Figure 36. Three Phase, Three Step, Half Wave Motor Controller

Three Phase Closed Loop Controller

The MC33033, by itself, is capable of open loop motor speed control. For closed loop speed control, the MC33033 requires an input voltage proportional to the motor speed. Traditionally this has been accomplished by means of a tachometer to generate the motor speed feedback voltage. Figure 37 shows an application whereby an MC33039, powered from the 6.25 V reference (Pin 7) of the MC33033, is used to generate the required feedback voltage without the need of a costly tachometer. The same Hall sensor signals used by the MC33033 for rotor position decoding are utilized by the MC33039. Every positive or negative going transition of the Hall sensor signals on any of the sensor lines causes the MC33039 to produce an output pulse of defined amplitude and time duration, as determined by the external resistor R_1 and capacitor C_1 . The resulting output

train of pulses present at Pin 5 of the MC33039 are integrated by the Error Amplifier of the MC33033 configured as an integrator, to produce a dc voltage level which is proportional to the motor speed. This speed proportional voltage establishes the PWM reference level at Pin 11 of the MC33033 motor controller and completes or closes the feedback loop. The MC33033 ouputs drive a TMOS power MOSFET 3-phase bridge. High current can be expected during conditions of start-up and when changing direction of the motor.

The system shown in Figure 37 is designed for a motor having 120/240 degrees Hall sensor electrical phasing. The system can easily be modified to accommodate 60/300 degree Hall sensor electrical phasing by removing the jumper (J₁) at Pin 18 of the MC33033.





Sensor Phasing Comparison

There are four conventions used to establish the relative phasing of the sensor signals in three phase motors. With six step drive, an input signal change must occur every 60 electrical degrees, however, the relative signal phasing is dependent upon the mechanical sensor placement. A comparison of the conventions in electrical degrees is shown in Figure 38. From the sensor phasing table (Figure 39), note that the order of input codes for 60° phasing is the reverse of 300°. This means the MC33033, when the $60^{\circ}/120^{\circ}$ select (Pin 18) and the FWD/REV (Pin 3) both in the high state (open), is configured to operate a 60° sensor phasing motor in the forward direction. Under the same conditions a 300° sensor phasing motor would operate equally well but in the reverse direction. One would simply have to reverse the FWD/REV switch (FWD/REV closed) in order to cause the 300° motor to also operate in the same direction. The same difference exists between the 120° and 240° conventions.

Figure 38. Sensor Phasing Comparison

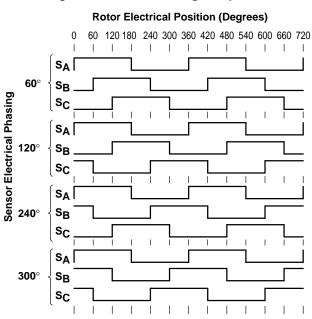


Figure 39. Sensor Phasing Table

	Sensor Electrical Phasing (Degrees)										
	60 °		120°				240 °			300 °	
SA	SB	s _C	SA	SB	s _C	s _A	SB	s _C	s _A	SB	s _C
1	0	0	1	0	1	1	1	0	1		1
1	1	0	1	0	0	1	0	0	1	1	0
1	1	1	1	1	0	1	0	1	1	0	0
0	1	1	0	1	0	0	0	1	0	0	0
0	0	1	0	1	1	0	1	1	0	0	1
0	0	0	0	0	1	0	1	0	0	1	1

In this data sheet, the rotor position has always been given in electrical degrees since the mechanical position is a function of the number of rotating magnetic poles. The relationship between the electrical and mechanical position is:

Electrical Degrees = Mechanical Degrees
$$\left(\frac{\#\text{Rotor Poles}}{2}\right)$$

An increase in the number of magnetic poles causes more electrical revolutions for a given mechanical revolution. General purpose three phase motors typically contain a four pole rotor which yields two electrical revolutions for one mechanical.

Two and Four Phase Motor Commutation

The MC33033 configured for 60° sensor inputs is capable of providing a four step output that can be used to drive two or four phase motors. The truth table in Figure 40 shows that by connecting sensor inputs S_B and S_C together, it is possible to truncate the number of drive output states from six to four. The output power switches are connected to B_T, C_T, B_B, and C_B. Figure 41 shows a four phase, four step, full wave motor control application. Power switch transistors Q₁ through Q₈ are Darlington type, each with an internal parasitic catch diode. With four step drive, only two rotor position sensors spaced at 90 electrical degrees are required. The commutation waveforms are shown in Figure 42.

Figure 43 shows a four phase, four step, half wave motor controller. It has the same features as the circuit in Figure 36, except for the deletion of speed adjust.

Figure 40. Two and Four Phase, Four Step,
Commutation Truth Table

MC33033 (60°/120° Select Pin Open)									
	Inputs		Outputs						
	Electrical g* = 90°		Top Drives Bottom Driv						
SA	SB	F/R	BT	B _T C _T		С _В			
1	0	1	1	1	0	1			
1	1	1	0	1	0	0			
0	1	1	1	0	0	0			
0	0	1	1	1	1	0			
1	0	0	1	0	0	0			
1	1	0	1	1	1	0			
0	1	0	1	1	0	1			
0	0	0	0	1	0	0			

*With MC33033 sensor input SB connected to SC

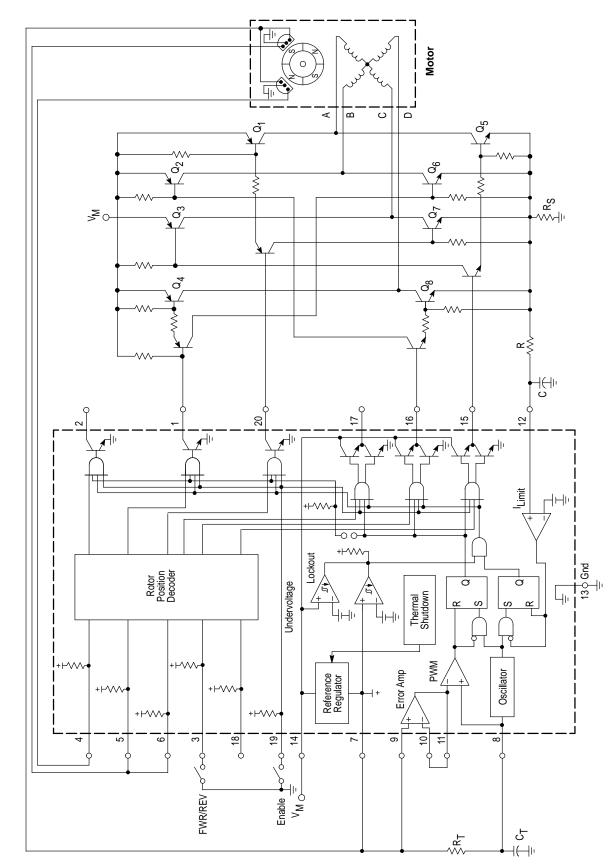
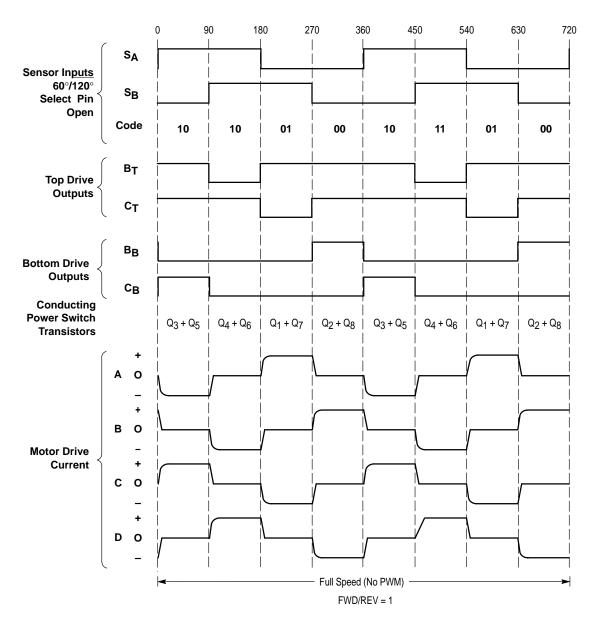


Figure 41. Four Phase, Four Step, Full Wave Controller

Figure 42. Four Phase, Four Step, Full Wave Commutation Waveforms



Rotor Electrical Position (Degrees)

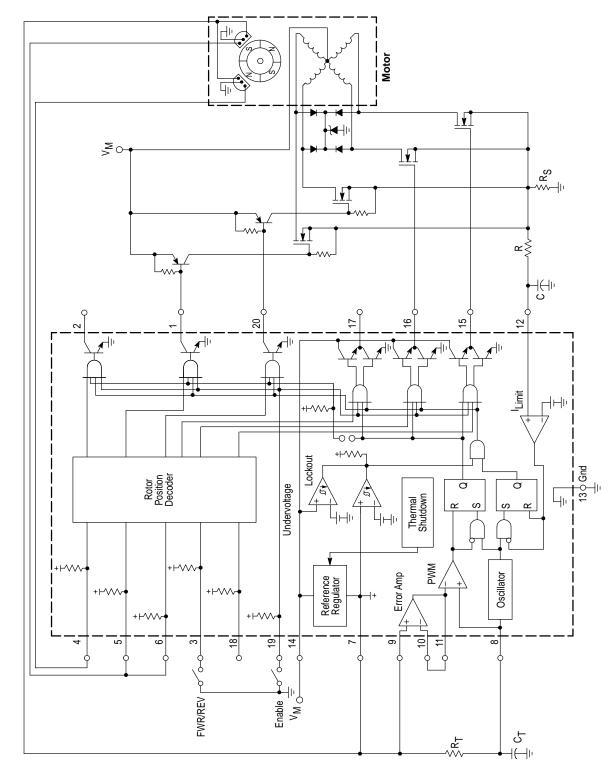


Figure 43. Four Phase, Four Step, Half Wave Motor Controller

Brush Motor Control

Though the MC33033 was designed to control brushless dc motors, it may also be used to control dc brush-type motors. Figure 44 shows an application of the MC33033 driving a H-bridge affording minimal parts count to operate a brush-type motor. Key to the operation is the input sensor code [100] which produces a top-left (Q_1) and a bottom-right (Q_3) drive when the controller's Forward/Reverse pin is at logic [1]; top-right (Q_4), bottom-left (Q_2) drive is realized when the Forward/Reverse pin is at logic [0]. This code supports the requirements necessary for H-bridge drive accomplishing both direction and speed control.

The controller functions in a normal manner with a pulse width modulated frequency of approximately 25 kHz. Motor speed is controlled by adjusting the voltage presented to the noninverting input of the Error Amplifier establishing the PWM's slice or reference level. Cycle–by–cycle current limiting of the motor current is accomplished by sensing the voltage (100 mV threshold) across the RS resistor to ground of the H–bridge motor current. The over current sense circuit makes it possible to reverse the direction of the motor, on the

fly, using the normal Forward/Reverse switch, and not have to completely stop before reversing.

LAYOUT CONSIDERATIONS

Do not attempt to construct any of the motor control circuits on wire–wrap or plug–in prototype boards. High frequency printed circuit layout techniques are imperative to prevent pulse jitter. This is usually caused by excessive noise pick–up imposed on the current sense or error amp inputs. The printed circuit layout should contain a ground plane with low current signal and high drive and output buffer grounds returning on separate paths back to the power supply input filter capacitor V_M. Ceramic bypass capacitors (0.01 μ F) connected close to the integrated circuit at V_{CC}, V_{ref} and error amplifiler noninverting input may be required depending upon circuit layout. This provides a low impedance path for filtering any high frequency noise. All high current loops should be kept as short as possible using heavy copper runs to minimize radiated EMI.

Figure 44. H–Bridge Brush–Type Controller

